LMV331 SINGLE, LMV393 DUAL, LMV339 QUAD GENERAL-PURPOSE LOW-VOLTAGE COMPARATORS

SLCS136C - AUGUST 1999 - REVISED APRIL 2000

- 2.7-V and 5-V Performance
- Low Supply Current:

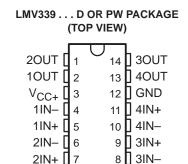
LMV331 . . . 60 μA Typ LMV393 . . . 100 μA Typ LMV339 . . . 170 μA Typ

- Input Common-Mode Voltage Range Includes Ground
- Low Output Saturation Voltage ... 200 mV Typ
- Package Options Include Plastic Small-Outline (D), Small-Outline Transistor (SOT-23 DBV, SC-70 DCK), and Thin Shrink Small-Outline (PW) Packages

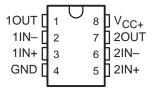
description

The LMV393 and LMV339 devices are low-voltage (2.7 V to 5.5 V) versions of the dual and quad comparators, LM393 and LM339, which operate from 5 V to 30 V. The LMV331 is the single-comparator version.

The LMV331, LMV339, and LMV393 are the most cost-effective solutions for applications where low-voltage operation, low power, space saving, and price are the primary specifications in circuit design for portable consumer products. These devices offer specifications that meet or exceed the familiar LM339 and LM393 devices at a fraction of the supply current.



LMV393 . . . D OR PW PACKAGE (TOP VIEW)



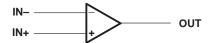
LMV331 . . . DBV OR DCK PACKAGE (TOP VIEW)



The LMV331 is available in the ultra-small DCK package, which is approximately one-half the size of the five-pin DBV package. The DCK package saves space on printed circuit boards and enables the design of small portable electronic devices. It also allows the designer to place the device closer to the signal source to reduce noise pickup and increase signal integrity.

The LMV331I, LMV339I, and LMV393I devices are characterized for operation from -40°C to 85°C.

logic symbol (each comparator)





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



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AVAILABLE OPTIONS

т.	PACKAGE	PACKAGED DEVICES			
TA	TYPE	SINGLE	DUAL	QUADRUPLE	
	5-pin SOT	LMV331IDCKR LMV331IDBVR	<u> </u>	_ _	
−40°C to 85°C	8-pin SOIC 8-pin TSSOP	o Po de litera	LMV393ID LMV393IPWR	_ _	
	14-pin SOIC 14-pin TSSOP	_	_	LMV339ID LMV339IPWR	

The D package is available taped and reeled. Add the suffix R to the device type (e.g., LMV393DR). The DCK, DBV, and PW packages are only available left-end taped and reeled.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V _{CC+} (see Note 1)		±5.5 V
Operating virtual junction temperature range		
Package thermal impedance, θ_{JA} (see Notes 3 and 4):		
	D (14-pin) package	
	DBV package	
	DCK package	. 389°C/W
	PW (8-pin) package	. 149°C/W
	PW (14-pin) package	. 113°C/W
Lead temperature 1,6 mm (1/16 inch) from case for 10	seconds: D or PW package	260°C
Storage temperature range, T _{stg}	→	35 to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values (except differential voltages and V_{CC+} specified for the measurement of I_{OS}) are with respect to the network GND.
 - 2. Differential voltages are at IN+ with respect to IN-.
 - 3. Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) T_A)/\theta_{JA}$. Selecting the maximum of 150°C can affect reliability.
 - 4. The package thermal impedance is calculated in accordance with JESD 51.

recommended operating conditions

		MIN	MAX	UNIT
V _{CC+}	Supply voltage (single-supply operation)	2.7	5.5	V
TA	Operating free-air temperature	-40	85	°C

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electrical characteristics at specified free-air temperature, V_{CC+} = 2.7 V, GND = 0 V (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	TA	MIN	TYP	MAX	UNIT
Vio	Input offset voltage		25°C		1.7	7	mV
$\alpha_{V_{10}}$	Average temperature coefficient of input offset voltage		-40°C to 85°C		5		μV/°C
1			25°C		10	250	nA
IB	Input bias current		–40°C to 85°C			400	
li o	Input offset current		25°C		5	50	nA
lio			–40°C to 85°C			150	
lo	Output current	V _O ≤ 1.5 V	25°C	5	23		mA
	Output leal-and aument		25°C		0.003		μΑ
	Output leakage current	current	–40°C to 85°C			1	
VICR	Common-mode input voltage range		25°C		-0.1 to 2		V
VSAT	Saturation voltage	I _O ≤ 1 mA	25°C		200		mV
	Supply current	LMV331 [†]	25°C		40	100	
Icc		LMV393 (both comparators)	25°C		70	140	μΑ
		LMV339 (all four comparators)	25°C		140	200	

[†] This device is product preview.

switching characteristics, T_A = 25°C, V_{CC+} = 2.7 V, R_L = 5.1 k Ω , GND = 0 V (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN TYP MAX	UNIT	
t _{PHL} P	Propagation delay, high- to low-level output switching	Input overdrive = 10 mV	1000		
		Input overdrive = 100 mV	350	ns	
^t PLH	Propagation delay, low- to high-level output switching	Input overdrive = 10 mV	500	nc	
		Input overdrive = 100 mV	400	ns	

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electrical characteristics at specified free-air temperature, $V_{CC+} = 5 \text{ V}$, GND = 0 V (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	TA	MIN	TYP	MAX	UNIT
\/10	Input offset voltage		25°C		1.7	7	mV
VIO	Input offset voltage		-40°C to 85°C			9	mv
$\alpha_{V_{IO}}$	Average temperature coefficient of input offset voltage		25°C		5		μV/°C
l.a	Input bigg ourrent		25°C		25	250	A
ΙΒ	Input bias current		-40°C to 85°C			400	nA
li o	Input offset current		25°C		2	50	nA
lio	input onset current		-40°C to 85°C			150	nA
IO	Output current	V _O ≤ 1.5 V	25°C	10	84		mA
	Output leakage current		25°C		0.003		μΑ
			-40°C to 85°C			1	
VICR	Common-mode input voltage range		25°C	-	-0.1 to 4.2		V
AVD	Large-signal differential voltage gain		25°C	20	50		V/mV
\/	Saturation voltage	I _O ≤ 4 mA	25°C		200	400	m∨
VSAT			-40°C to 85°C			700	
	Supply current	LMV331 [†]	25°C		60	120	μΑ
Icc			-40°C to 85°C			150	
		LMV393 (both comparators)	25°C		100	200	
			-40°C to 85°C			250	
		LAN(000 (-III (25°C		170	300	
		LMV339 (all four comparators)	-40°C to 85°C			350	

[†] This device is product preview.

switching characteristics, T_A = 25°C, V_{CC+} = 5 V, R_L = 5.1 k Ω , GND = 0 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN TYP MAX	UNIT
tPHL	Propagation delay, high- to low-level output switching	Input overdrive = 10 mV	600	ns
		Input overdrive = 100 mV	200	
tPLH	Drangation delay law to high layer autout authors	Input overdrive = 10 mV	450	ns
	Propagation delay, low- to high-level output switching	Input overdrive = 100 mV	300	

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